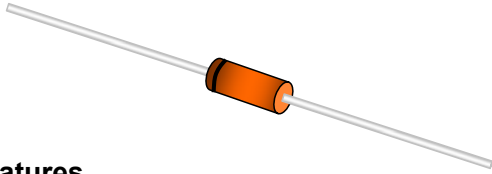


Small Signal Diode



Features

- ✧ Wide zener voltage range selection: 2.0V to 75V
- ✧ Vz Tolerance Selection of $\pm 5\%$
- ✧ Designed for through-Hole Device Type Mounting
- ✧ Hermetically Sealed Glass
- ✧ Pb free version and RoHS compliant
- ✧ High reliability glass passivation insuring parameter stability and protection against junction contamination

Mechanical Data

- ✧ Case : DO-35 package (SOD-27)
- ✧ Lead: Axial leads, solderable per MIL-STD-202, Method 205
- ✧ High temperature soldering guaranteed: 260°C/10s
- ✧ Polarity: Indicated by cathode band
- ✧ Weight : 109 $\pm$ 4 mg

Ordering Information

Part No.	Package code	Package	Packing
BZX79C2V0-75	A0	DO-35	5Kpcs / Ammo
BZX79C2V0-75	R0	DO-35	10Kpcs / 14" Reel

Maximum Ratings and Electrical Characteristics

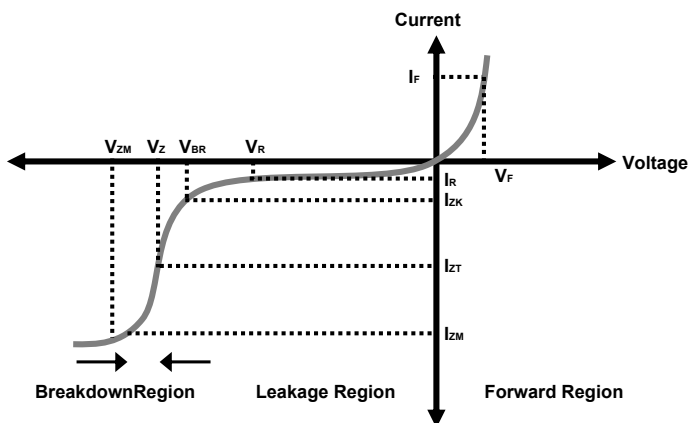
Rating at 25°C ambient temperature unless otherwise specified.

Maximum Ratings

Type Number	Symbol	Value	Units
Power Dissipation	P_D	500	mW
Maximum Forward Voltage @ $I_F=100\text{mA}$	V_F	1.5	V
Thermal Resistance (Junction to Ambient) (Note 1)	$R_{\theta JA}$	300	°C/W
Storage Temperature Range	T_J, T_{STG}	-65 to + 175	°C

Notes: 1. Valid provided that electrodes are kept at ambient temperature

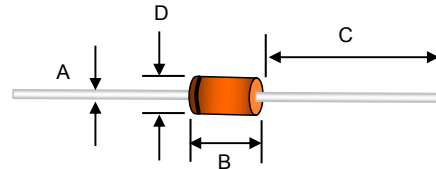
Zener I vs. V Characteristics



- V_{BR} : Voltage at I_{ZK}
- I_{ZK} : Test current for voltage V_{BR}
- Z_{ZK} : Dynamic impedance at I_{ZK}
- I_{ZT} : Test current for voltage V_Z
- V_Z : Voltage at current I_{ZT}
- Z_{ZT} : Dynamic impedance at I_{ZT}
- I_{ZM} : Maximum steady state current
- V_{ZM} : Voltage at I_{ZM}

BZX79C2V0-BZX79C75 500mW, 5% Tolerance Zener Diode

DO-35 Axial Lead HERMETICALLY SEALED GLASS



Dimensions	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	0.45	0.55	0.018	0.022
B	3.05	5.08	0.120	0.201
C	25.40	38.10	1.000	1.500
D	1.53	2.28	0.060	0.090

Small Signal Diode
Electrical Characteristics

Ta = 25°C unless otherwise noted

V_F Forward Voltage = 1.5V Maximum @ I_F = 100 mA for all part numbers

Part Number	Marking Code	V _Z @ I _{ZT} (Volt)			I _{ZT} (mA)	Z _{ZT} @ I _{ZT} (Ω) Max	I _{ZK} (mA)	Z _{ZK} @ I _{ZK} (Ω) Max	I _R @ V _R (μA) Max	V _R (V)
		Min	Nom	Max						
BZX79C2V0	BZX79C2V0	1.9	2.0	2.1	5	100	1.0	600	150	1.0
BZX79C2V2	BZX79C2V2	2.1	2.2	2.3	5	100	1.0	600	150	1.0
BZX79C2V4	BZX79C2V4	2.3	2.4	2.5	5	100	1.0	600	100	1.0
BZX79C2V7	BZX79C2V7	2.6	2.7	2.8	5	100	1.0	600	75	1.0
BZX79C3V0	BZX79C3V0	2.9	3.0	3.2	5	95	1.0	600	50	1.0
BZX79C3V3	BZX79C3V3	3.1	3.3	3.5	5	95	1.0	600	25	1.0
BZX79C3V6	BZX79C3V6	3.4	3.6	3.8	5	90	1.0	600	15	1.0
BZX79C3V9	BZX79C3V9	3.7	3.9	4.1	5	90	1.0	600	10	1.0
BZX79C4V3	BZX79C4V3	4.1	4.3	4.5	5	90	1.0	600	5	1.0
BZX79C4V7	BZX79C4V7	4.5	4.7	4.9	5	80	1.0	500	3	2.0
BZX79C5V1	BZX79C5V1	4.8	5.1	5.4	5	60	1.0	480	2	2.0
BZX79C5V6	BZX79C5V6	5.3	5.6	5.9	5	40	1.0	400	1	2.0
BZX79C6V2	BZX79C6V2	5.9	6.2	6.5	5	10	1.0	150	3	4.0
BZX79C6V8	BZX79C6V8	6.5	6.8	7.1	5	15	1.0	80	2	4.0
BZX79C7V5	BZX79C7V5	7.1	7.5	7.9	5	15	1.0	80	1	5.0
BZX79C8V2	BZX79C8V2	7.8	8.2	8.6	5	15	1.0	80	0.7	5.0
BZX79C9V1	BZX79C9V1	8.6	9.1	9.6	5	15	1.0	100	0.5	6.0
BZX79C10	BZX79C10	9.5	10	10.5	5	20	1.0	150	0.2	7.0
BZX79C11	BZX79C11	10.5	11	11.6	5	20	1.0	150	0.1	8.0
BZX79C12	BZX79C12	11.4	12	12.6	5	25	1.0	150	0.1	8.0
BZX79C13	BZX79C13	12.4	13	13.7	5	30	1.0	170	0.1	8.0
BZX79C15	BZX79C15	14.3	15	15.8	5	30	1.0	200	0.05	10.5
BZX79C16	BZX79C16	15.2	16	16.8	5	40	1.0	200	0.05	11.2
BZX79C18	BZX79C18	17.1	18	18.9	5	45	1.0	225	0.05	12.6
BZX79C20	BZX79C20	19.0	20	21.0	5	55	1.0	225	0.05	14.0
BZX79C22	BZX79C22	20.9	22	23.1	5	55	1.0	250	0.05	15.4
BZX79C24	BZX79C24	22.8	24	25.2	5	70	1.0	250	0.05	16.8
BZX79C27	BZX79C27	25.7	27	28.4	2	80	0.5	300	0.05	18.9
BZX79C30	BZX79C30	28.5	30	31.5	2	80	0.5	300	0.05	21.0
BZX79C33	BZX79C33	31.4	33	34.7	2	80	0.5	325	0.05	23.1
BZX79C36	BZX79C36	34.2	36	37.8	2	90	0.5	350	0.05	25.2
BZX79C39	BZX79C39	37.1	39	41.0	2	130	0.5	350	0.05	27.3
BZX79C43	BZX79C43	40.9	43	45.2	2	150	0.5	375	0.05	30.1
BZX79C47	BZX79C47	44.7	47	49.4	2	170	0.5	375	0.05	32.9
BZX79C51	BZX79C51	48.5	51	53.6	2	180	0.5	400	0.05	35.7
BZX79C56	BZX79C56	53.2	56	58.8	2	200	0.5	425	0.05	39.2
BZX79C62	BZX79C62	58.9	62	65.1	2.5	215	0.5	1000	0.05	43.4
BZX79C68	BZX79C68	64.6	68	71.4	2.5	240	0.5	1000	0.05	47.6
BZX79C75	BZX79C75	71.3	75	78.8	2.5	255	0.5	1000	0.05	52.5

Notes:

1. The Zener Voltage (V_Z) is tested under pulse condition of 10ms
2. The device numbers listed have a standard tolerance on the nominal zener voltage of **±5%**.
3. For detailed information on price, availability and delivery of nominal zener voltages between the voltages shown and tighter voltage tolerances, contact your nearest **Taiwan semiconductor** representative.
4. The zener impedance is derived from the 60-cycle ac voltage, which results when an ac current having an rms value equal to 10% of the DC zener current

Small Signal Diode

Rating and Sharacteristic Curves

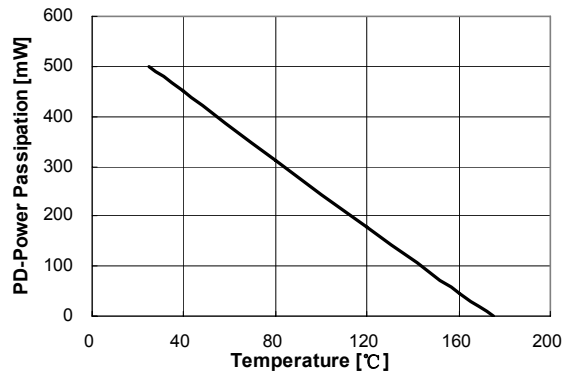


Figure 1. Power Dissipation vs Ambient Temperature
Valid provided leads at a distance of 0.8mm from case are kept at ambient temperature

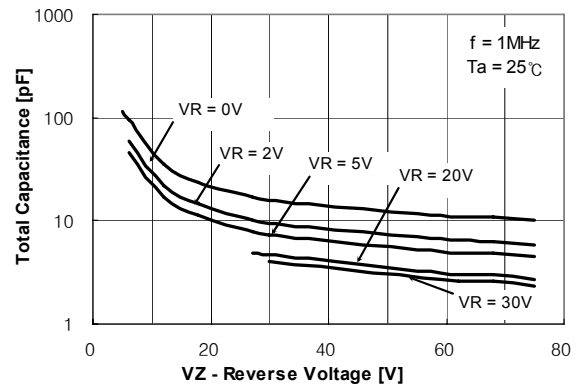


Figure 2. Total Capacitance

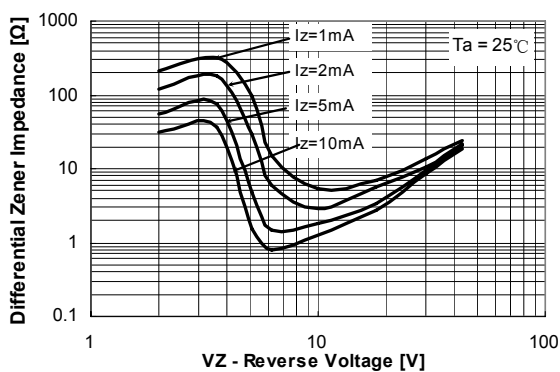


Figure 3. Differential Impedance vs. Zener Voltage

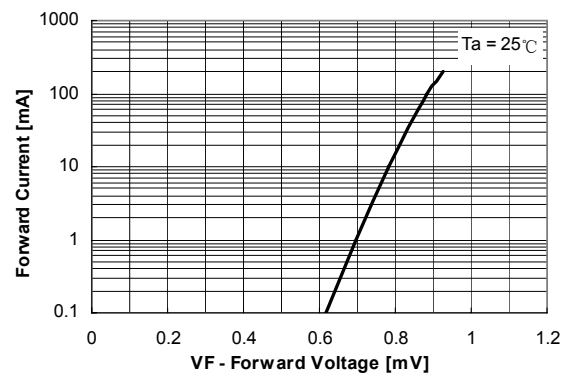


Figure 4. Forward Current vs. Forward Voltage

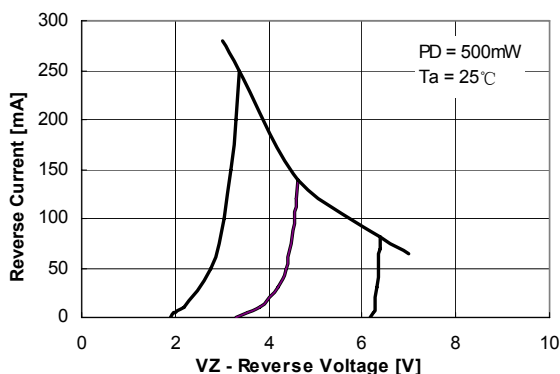


Figure 5. Reverse Current vs. Reverse Voltage

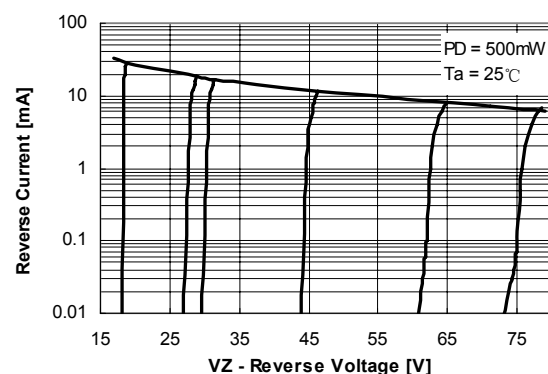
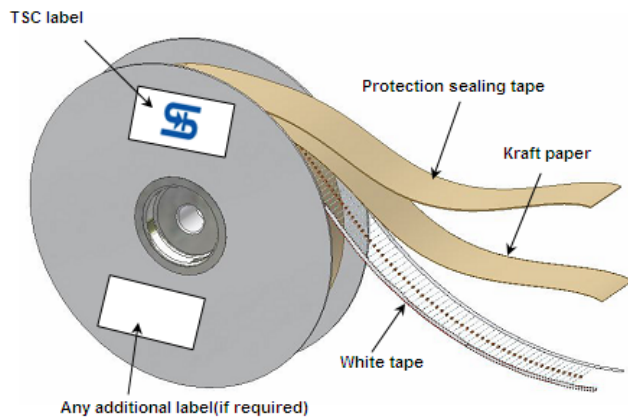


Figure 6. Reverse Current vs. Reverse Voltage

Small Signal Diode

Tape & Reel specification



BZX79C2V0-BZX79C75 500mW,5% Tolerance Zener Diode

Item	Symbol	Dimension(mm)
Overall width	A	64+1.69/-0.69
Tape spacing	B	52.0+/-0.69
Component Pitch	C	5.08+/-0.40
Untaped lead	L1-L2	+/-0.69
Bent	K	1.2 Max
Tape Mismatch	E	0.55(MAX)
Glass offset	F	0.69(MAX)
Taped lead	G	3.2Min
lead beyond tape	H	0
Reel outside diameter	D	260+/-3
Reel inner diameter	D1	48+/-1
Feed hole width	D2	20+/-0.5
Reel width	W1	72+3/-1

